

# **Excellent Integrated System Limited**

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Texas Instruments CD74HCT165E

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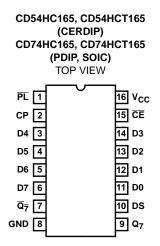
Data sheet acquired from Harris Semiconductor SCHS156C

February 1998 - Revised October 2003

#### Features

- Buffered Inputs
- Asynchronous Parallel Load
- Complementary Outputs
- Fanout (Over Temperature Range)
- Wide Operating Temperature Range ... -55°C to 125°C
- Balanced Propagation Delay and Transition Times
- Significant Power Reduction Compared to LSTTL Logic ICs
- HC Types
  - 2V to 6V Operation
  - High Noise Immunity: N<sub>IL</sub> = 30%, N<sub>IH</sub> = 30% of V<sub>CC</sub> at V<sub>CC</sub> = 5V
- HCT Types
  - 4.5V to 5.5V Operation
  - Direct LSTTL Input Logic Compatibility, V<sub>IL</sub>= 0.8V (Max), V<sub>IH</sub> = 2V (Min)
  - CMOS Input Compatibility,  $I_{I} \leq 1 \mu A$  at  $V_{OL}, \, V_{OH}$

#### Pinout



# CD54HC165, CD74HC165, CD54HCT165, CD74HCT165

### High-Speed CMOS Logic 8-Bit Parallel-In/Serial-Out Shift Register

#### Description

The 'HC165 and 'HCT165 are 8-bit parallel or serial-in shift registers with complementary serial outputs ( $Q_7$  and  $\overline{Q}_{\overline{7}}$ ) available from the last stage. When the parallel load ( $\overline{PL}$ ) input is LOW, parallel data from the D0 to D7 inputs are loaded into the register asynchronously. When the  $\overline{PL}$  is HIGH, data enters the register serially at the DS input and shifts one place to the right ( $Q_0 \rightarrow Q_1 \rightarrow Q_2$ , etc.) with each positive-going clock transition. This feature allows parallel-to-serial converter expansion by typing the  $Q_7$  output to the DS input of the succeeding device.

For predictable operation the LOW-to-HIGH transition of  $\overline{CE}$  should only take place while CP is HIGH. Also, CP and  $\overline{CE}$  should be LOW before the LOW-to-HIGH transition of PL to prevent shifting the data when  $\overline{PL}$  goes HIGH.

#### **Ordering Information**

PART NUMBER	TEMP. RANGE ( <sup>o</sup> C)	PACKAGE
CD54HC165F3A	-55 to 125	16 Ld CERDIP
CD54HCT165F3A	-55 to 125	16 Ld CERDIP
CD74HC165E	-55 to 125	16 Ld PDIP
CD74HC165M	-55 to 125	16 Ld SOIC
CD74HC165MT	-55 to 125	16 Ld SOIC
CD54HC165M96	-55 to 125	16 Ld SOIC
CD74HCT165E	-55 to 125	16 Ld PDIP
CD74HCT165M	-55 to 125	16 Ld SOIC
CD74HCT165MT	-55 to 125	16 Ld SOIC
CD54HCT165M96	-55 to 125	16 Ld SOIC

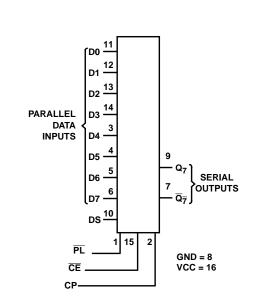
NOTE: When ordering, use the entire part number. The suffix 96 denotes tape and reel. The suffix T denotes a small-quantity reel of 250.

CAUTION: These devices are sensitive to electrostatic discharge. Users should follow proper IC Handling Procedures. Copyright © 2003, Texas Instruments Incorporated



Functional Diagram

### CD54HC165, CD74HC165, CD54HCT165, CD74HCT165



#### TRUTH TABLE

			INPUTS			Q <sub>n</sub> RE	GISTER	OUTPUTS		
OPERATING MODE	PL	CE	СР	DS	D0 - D7	Q <sub>0</sub>	Q <sub>1</sub> - Q <sub>6</sub>	Q <sub>7</sub>	<b>Q</b> 7	
Parallel Load	L	х	х	х	L	L	L-L	L	н	
	L	х	х	х	н	н	H-H	Н	L	
Serial Shift	Н	L	Ŷ	I	х	L	9 <sub>0 -</sub> 9 <sub>5</sub>	9 <sub>6</sub>	$\overline{q}_{6}$	
	Н	L	Ŷ	h	х	н	9 <sub>0</sub> - 95	9 <sub>6</sub>	$\overline{q}_{6}$	
Hold Do Nothing	Н	н	х	х	х	9 <sub>0</sub>	91 - 96	q <sub>7</sub>	q <sub>7</sub>	

H =High Voltage Level

h = High Voltage Level One Set-up Time Prior To The Low-to-high Clock Transition

I = Low Voltage Level One Set-up Time Prior To The Low-to-high Clock Transition

L = Low Voltage Level

X = Don't Care

 $\uparrow$  = Transition from Low to High Level

 $q_n$  = Lower Case Letters Indicate The State Of the Reference Output Clock Transition



#### **Absolute Maximum Ratings**

DC Supply Voltage, V <sub>CC</sub>
DC Input Diode Current, $I_{IK}$ For V <sub>I</sub> < -0.5V or V <sub>I</sub> > V <sub>CC</sub> + 0.5V±20mA
DC Output Diode Current, $I_{OK}$
For $V_0 < -0.5V$ or $V_0 > V_{CC} + 0.5V$
DC Drain Current per Output, IO
For $V_0 < -0.5V V_0 > V_{CC} + 0.5V \dots \pm 25$ mA
DC Output Source or Sink Current per Output Pin, IO
For $V_0 > -0.5V$ or $V_0 < V_{CC} + 0.5V$ ±25mA
DC V <sub>CC</sub> or Ground Current, I <sub>CC or</sub> I <sub>GND</sub> ±50mA
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#### **Thermal Information**

Thermal Resistance (Typical, Note 1)	θ <sub>JA</sub> ( <sup>o</sup> C/W)
E (PDIP) Package	. 67
M (SOIC) Package	. 73
Maximum Junction Temperature	150 <sup>0</sup> C
Maximum Storage Temperature Range	65 <sup>0</sup> C to 150 <sup>0</sup> C
Maximum Lead Temperature (Soldering 10s)	
(SOIC - Lead Tips Only)	

#### **Operating Conditions**

Temperature Range $(T_A)$
HC Types
HCT Types4.5V to 5.5V
DC Input or Output Voltage, V <sub>I</sub> , V <sub>O</sub> 0V to V <sub>CC</sub>
Input Rise and Fall Time
2V
4.5V 500ns (Max)
6V

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

#### NOTE:

1. The package thermal impedance is calculated in accordance with JESD 51-7.

#### **DC Electrical Specifications**

			ST ITIONS		25 <sup>0</sup> C			-40°C TO 85°C		-55°C TO 125°C		
PARAMETER	SYMBOL	V <sub>I</sub> (V)	I <sub>O</sub> (mA)	V <sub>CC</sub> (V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
HC TYPES		-								-	-	
High Level Input	VIH	-	-	2	1.5	-	-	1.5	-	1.5	-	V
Voltage				4.5	3.15	-	-	3.15	-	3.15	-	V
				6	4.2	-	-	4.2	-	4.2	-	V
Low Level Input	VIL	-	-	2	-	-	0.5	-	0.5	-	0.5	V
Voltage				4.5	-	-	1.35	-	1.35	-	1.35	V
				6	-	-	1.8	-	1.8	-	1.8	V
High Level Output Voltage CMOS Loads	V <sub>OH</sub>	V <sub>IH</sub> or	-0.02	2	1.9	-	-	1.9	-	1.9	-	V
		VIL	-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V
			-0.02	6	5.9	-	-	5.9	-	5.9	-	V
High Level Output			-4	4.5	3.98	-	-	3.84	-	3.7	-	V
Voltage TTL Loads			-5.2	6	5.48	-	-	5.34	-	5.2	-	V
Low Level Output	V <sub>OL</sub>	V <sub>IH</sub> or	0.02	2	-	-	0.1	-	0.1	-	0.1	V
Voltage CMOS Loads		VIL	0.02	4.5	-	-	0.1	-	0.1	-	0.1	V
0			0.02	6	-	-	0.1	-	0.1	-	0.1	V
Low Level Output			4	4.5	-	-	0.26	-	0.33	-	0.4	V
Voltage TTL Loads			5.2	6	-	-	0.26	-	0.33	-	0.4	V
Input Leakage Current	lı	V <sub>CC</sub> or GND	-	6	-	-	±0.1	-	±1	-	±1	μA

#### 3



			ST ITIONS			25 <sup>0</sup> C		-40 <sup>0</sup> C 1	O 85ºC	-55°C T	O 125 <sup>0</sup> C	
PARAMETER	SYMBOL	V <sub>I</sub> (V)	I <sub>O</sub> (mA)	V <sub>CC</sub> (V)	MIN	ТҮР	MAX	MIN	MAX	MIN	MAX	UNITS
Quiescent Device Current	Icc	V <sub>CC</sub> or GND	0	6	-	-	8	-	80	-	160	μA
HCT TYPES												
High Level Input Voltage	V <sub>IH</sub>	-	-	4.5 to 5.5	2	-	-	2	-	2	-	V
Low Level Input Voltage	V <sub>IL</sub>	-	-	4.5 to 5.5	-	-	0.8	-	0.8	-	0.8	V
High Level Output Voltage CMOS Loads	V <sub>OH</sub>	V <sub>IH</sub> or V <sub>IL</sub>	-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V
High Level Output Voltage TTL Loads			-4	4.5	3.98	-	-	3.84	-	3.7	-	V
Low Level Output Voltage CMOS Loads	V <sub>OL</sub>	V <sub>IH</sub> or V <sub>IL</sub>	0.02	4.5	-	-	0.1	-	0.1	-	0.1	V
Low Level Output Voltage TTL Loads			4	4.5	-	-	0.26	-	0.33	-	0.4	V
Input Leakage Current	lı	V <sub>CC</sub> to GND	0	5.5	-	-	±0.1	-	±1	-	±1	μA
Quiescent Device Current	ICC	V <sub>CC</sub> or GND	0	5.5	-	-	8	-	80	-	160	μA
Additional Quiescent Device Current Per Input Pin: 1 Unit Load	ΔI <sub>CC</sub> (Note 2)	V <sub>CC</sub> -2.1	-	4.5 to 5.5	-	100	360	-	450	-	490	μΑ

NOTE:

2. For dual-supply systems theoretical worst case (V<sub>I</sub> = 2.4V, V<sub>CC</sub> = 5.5V) specification is 1.8mA.

#### **HCT Input Loading Table**

INPUT	UNIT LOADS						
DS, D0 to D7	0.35						
CP, PL	0.65						

NOTE: Unit Load is  $\Delta I_{CC}$  limit specified in DC Electrical Specifications table, e.g.  $360\mu A$  max at  $25^{\circ}C$ .

#### **Prerequisite For Switching Specifications**

			25°C		-40 <sup>0</sup> C T	O 85°C	-55 <sup>0</sup> C T		
PARAMETER	SYMBOL	V <sub>CC</sub> (V)	MIN	MAX	MIN	MAX	MIN	MAX	UNITS
HC TYPES	-								_
CP Pulse Width	t <sub>WL,</sub> t <sub>WH</sub>	2	80	-	100	-	120	-	ns
		4.5	16	-	20	-	24	-	ns
		6	14	-	17	-	20	-	ns



			25	oc	-40 <sup>0</sup> C 1	О 85 <sup>0</sup> С	-55 <sup>0</sup> C T	O 125 <sup>0</sup> C	
PARAMETER	SYMBOL	V <sub>CC</sub> (V)	MIN	МАХ	MIN	MAX	MIN	МАХ	UNITS
PL Pulse Width	t <sub>WL</sub>	2	80	-	100	-	120	-	ns
		4.5	16	-	20	-	24	-	ns
		6	14	-	17	-	20	-	ns
Set-up Time	ts∪	2	80	-	100	-	120	-	ns
DS to CP		4.5	16	-	20	-	24	-	ns
		6	14	-	17	-	20	-	ns
CE to CP	t <sub>SU(L)</sub>	2	80	-	100	-	120	-	ns
		4.5	16	-	20	-	24	-	ns
		6	14	-	17	-	20	-	ns
D0-D7 to PL	ts∪	2	80	-	100	-	120	-	ns
		4.5	16	-	20	-	24	-	ns
		6	14	-	17	-	20	-	ns
Hold Time	t <sub>H</sub>	2	35	-	45	-	55	-	ns
DS to CP or $\overline{CE}$		4.5	7	-	9	-	11	-	ns
		6	6	-	8	-	9	-	ns
CE to CP	t <sub>H</sub>	2	0	-	0	-	0	-	ns
		4.5	0	-	0	-	0	-	ns
		6	0	-	0	-	0	-	ns
Recovery Time	tREC	2	100	-	125	-	150	-	ns
PL to CP		4.5	20	-	25	-	30	-	ns
		6	17	-	21	-	26	-	ns
Maximum Clock Pulse	f <sub>MAX</sub>	2	6	-	5	-	4	-	MHz
Frequency		4.5	30	-	24	-	20	-	MHz
		6	35	-	28	-	24	-	MHz
HCT TYPES									-
CP Pulse Width	t <sub>WL</sub> , t <sub>WH</sub>	4.5	18	-	23	-	27	-	ns
PL Pulse Width	t <sub>WL</sub>	4.5	20	-	25	-	30	-	ns
Set-up Time DS to CP	ts∪	4.5	20	-	25	-	30	-	ns
CE to CP	<sup>t</sup> SU(L)	4.5	20	-	25	-	30	-	ns
D0-D7 to PL	ts∪	6	20	-	25	-	30	-	ns
Hold Time DS to CP or CE	tн	4.5	7	-	9	-	11	-	ns
CE to CP	t <sub>S</sub> , t <sub>H</sub>	4.5	0	-	0	-	0	-	ns
Recovery Time PL to CP	<sup>t</sup> REC	4.5	20	-	25	-	30	-	ns
Maximum Clock Pulse Frequency	f <sub>MAX</sub>	4.5	27	-	22	-	18	-	MHz



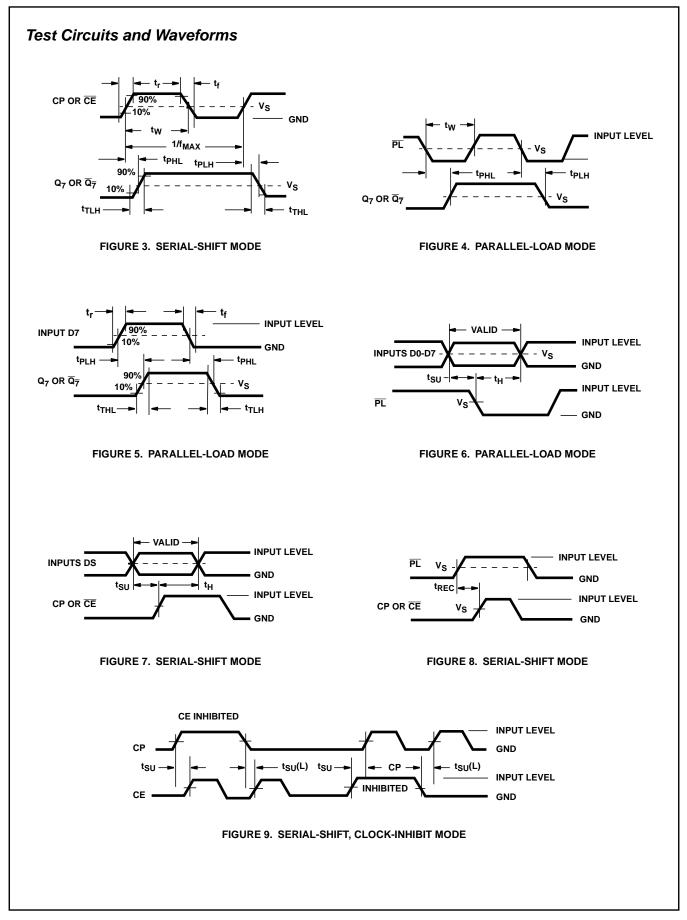
		TEST		25	o <sub>o</sub> C	-40°C TO 85°C	-55°C TO 125°C	
PARAMETER	SYMBOL	CONDITIONS	V <sub>CC</sub> (V)	TYP	MAX	МАХ	MAX	UNITS
HC TYPES	- <u> </u>	•	·		!			
Propagation Delay	t <sub>PLH</sub> , t <sub>PHL</sub>	C <sub>L</sub> = 50pF	2	-	165	205	250	ns
CP or $\overline{CE}$ to $Q_7$ or $\overline{Q}_{\overline{7}}$	1		4.5	-	33	41	50	ns
		C <sub>L</sub> = 15pF	5	13	-	-	-	ns
		C <sub>L</sub> = 50pF	6	-	28	35	43	ns
$\overline{PL}$ to $Q_7$ or $\overline{Q}_{\overline{7}}$	t <sub>PLH</sub> , t <sub>PHL</sub>	C <sub>L</sub> = 50pF	2	-	175	220	265	ns
			4.5	-	35	44	53	ns
		C <sub>L</sub> = 15pF	5	14	-	-	-	ns
		C <sub>L</sub> = 50pF	6	-	30	37	45	ns
D7 to $Q_7$ or $\overline{Q}_{\overline{7}}$	t <sub>PLH</sub> , t <sub>PHL</sub>	C <sub>L</sub> = 50pF	2	-	150	190	225	ns
			4.5	-	30	38	45	ns
		C <sub>L</sub> = 15pF	5	12	-	-	-	ns
		C <sub>L</sub> = 50pF	6	-	26	33	38	ns
Output Transition Times	t <sub>TLH</sub> , t <sub>THL</sub>	C <sub>L</sub> = 50pF	2	-	75	95	110	ns
			4.5	-	15	19	22	ns
			6	-	13	16	19	ns
Input Capacitance	C <sub>IN</sub>	-	-	-	10	10	10	pF
Power Dissipation Capacitance (Notes 3, 4)	C <sub>PD</sub>	-	5	17	-	-	-	pF
HCT TYPES	<b>!</b>							
Propagation Delay	t <sub>PLH</sub> , t <sub>PHL</sub>	C <sub>L</sub> = 50pF	4.5	-	40	50	60	ns
CP or $\overline{CE}$ to $Q_7$ or $\overline{Q}_{\overline{7}}$		C <sub>L</sub> = 15pF	5	17	-	-	-	ns
$\overline{PL}$ to $Q_7$ or $\overline{Q}_{\overline{7}}$	t <sub>PLH</sub> , t <sub>PHL</sub>	C <sub>L</sub> = 50pF	4.5	-	40	50	60	ns
		C <sub>L</sub> = 15pF	5	17	-	-	-	ns
D7 to $Q_7$ or $\overline{Q}_{\overline{7}}$	t <sub>PLH</sub> , t <sub>PHL</sub>	C <sub>L</sub> = 50pF	4.5	-	35	44	53	ns
		C <sub>L</sub> = 15pF	5	14	-	-	-	ns
Output Transition Times	t <sub>TLH</sub> , t <sub>THL</sub>	C <sub>L</sub> = 50pF	4.5	-	15	19	22	ns
Input Capacitance	C <sub>IN</sub>	C <sub>L</sub> = 50pF	-	-	10	10	10	pF
Power Dissipation Capacitance (Notes 3, 4)	C <sub>PD</sub>	-	5	24		-	-	pF

NOTES:

3. C<sub>PD</sub> is used to determine the dynamic power consumption, per package.

4.  $P_D = V_{CC}^2 f_i + \Sigma (C_L V_{CC}^2 + f_O)$  where  $f_i$  = Input Frequency,  $f_O$  = Output Frequency,  $C_L$  = Output Load Capacitance,  $V_{CC}$  = Supply Voltage.







10-Jun-2014

#### PACKAGING INFORMATION

Orderable Device	Status	Package Type		Pins		Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
5962-8685501EA	ACTIVE	CDIP	J	16	1	TBD	A42	N / A for Pkg Type	-55 to 125	5962-8685501EA CD54HCT165F3A	Samples
CD54HC165F3A	ACTIVE	CDIP	J	16	1	TBD	A42	N / A for Pkg Type	-55 to 125	8409501EA CD54HC165F3A	Samples
CD54HCT165F3A	ACTIVE	CDIP	J	16	1	TBD	A42	N / A for Pkg Type	-55 to 125	5962-8685501EA CD54HCT165F3A	Samples
CD74HC165E	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-55 to 125	CD74HC165E	Samples
CD74HC165EE4	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-55 to 125	CD74HC165E	Samples
CD74HC165M	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC165M	Samples
CD74HC165M96	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC165M	Samples
CD74HC165M96G4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC165M	Samples
CD74HC165ME4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC165M	Samples
CD74HC165MG4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC165M	Samples
CD74HC165MT	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC165M	Samples
CD74HC165MTE4	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC165M	Samples
CD74HCT165E	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-55 to 125	CD74HCT165E	Samples
CD74HCT165EE4	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-55 to 125	CD74HCT165E	Samples
CD74HCT165M	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT165M	Samples
CD74HCT165M96	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU   CU SN	Level-1-260C-UNLIM	-55 to 125	HCT165M	Samples
CD74HCT165M96E4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT165M	Samples

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Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
CD74HCT165M96G4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT165M	Samples
CD74HCT165ME4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT165M	Samples
CD74HCT165MG4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT165M	Samples
CD74HCT165MT	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT165M	Samples

<sup>(1)</sup> The marketing status values are defined as follows: ACTIVE: Product device recommended for new designs.

ACTIVE: Froude device recommended on new designs. LIFEBUY: Thas announced that the device will be discontinued, and a lifetime-buy period is in effect. NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design. PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details. **TBD:** The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): Tis terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width

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OTHER QUALIFIED VERSIONS OF CD54HC165, CD54HC165, CD74HC165, CD74HC165 :

• Catalog: CD74HC165, CD74HCT165

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Military: CD54HC165, CD54HCT165

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Military QML certified for Military and Defense Applications

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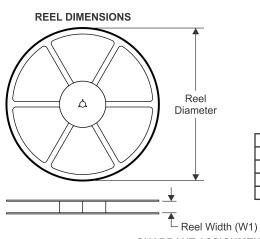
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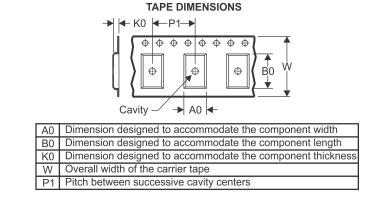


# PACKAGE MATERIALS INFORMATION

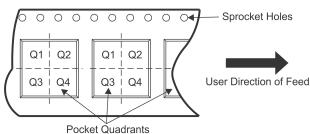
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# TAPE AND REEL INFORMATION





#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



Il dimensions are nominal Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD74HC165M96	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
CD74HC165M96	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
CD74HCT165M96	SOIC	D	16	2500	330.0	16.8	6.5	10.3	2.1	8.0	16.0	Q1
CD74HCT165M96	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
CD74HCT165M96G4	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1



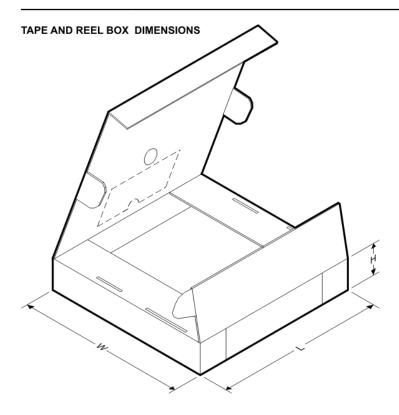
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# PACKAGE MATERIALS INFORMATION

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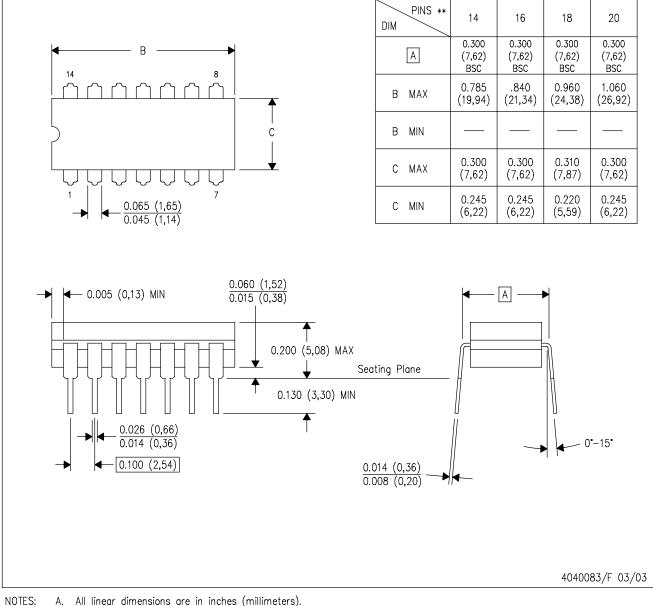
\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CD74HC165M96	SOIC	D	16	2500	333.2	345.9	28.6
CD74HC165M96	SOIC	D	16	2500	367.0	367.0	38.0
CD74HCT165M96	SOIC	D	16	2500	364.0	364.0	27.0
CD74HCT165M96	SOIC	D	16	2500	333.2	345.9	28.6
CD74HCT165M96G4	SOIC	D	16	2500	333.2	345.9	28.6



J (R-GDIP-T\*\*) 14 LEADS SHOWN

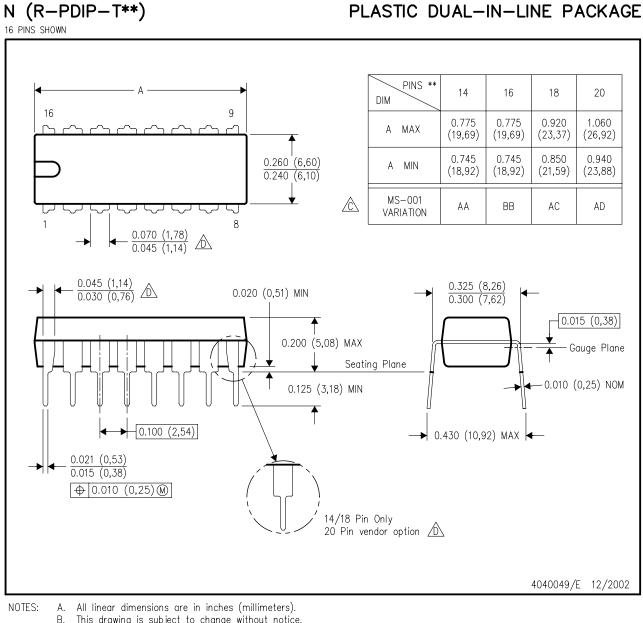
# CERAMIC DUAL IN-LINE PACKAGE



- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.



### **MECHANICAL DATA**



- This drawing is subject to change without notice.
- 🖄 Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.

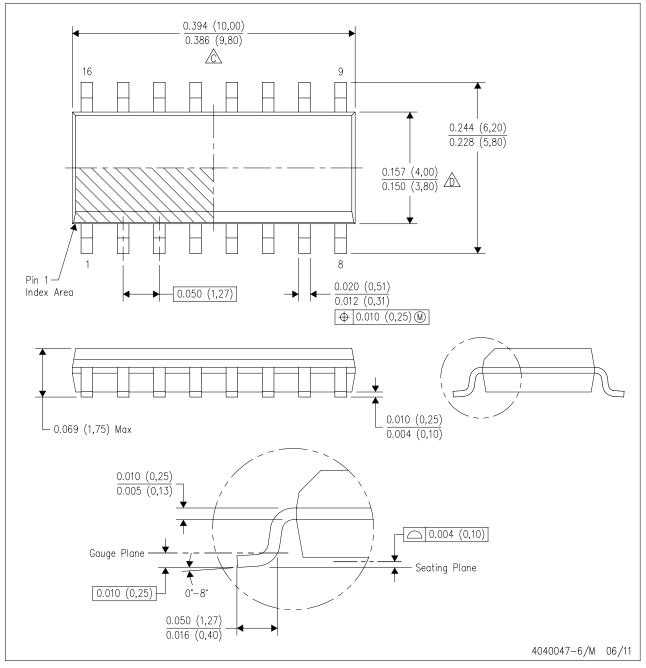




### **MECHANICAL DATA**

# D (R-PDSO-G16)

PLASTIC SMALL OUTLINE



NOTES:

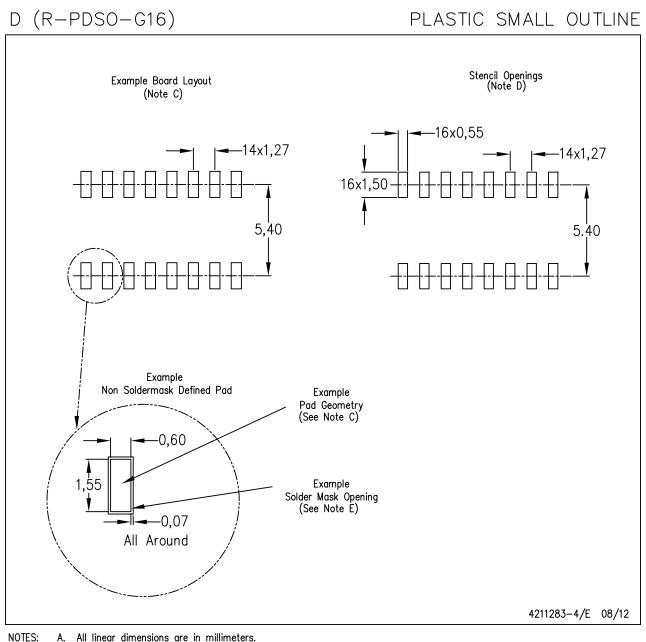
A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AC.





# LAND PATTERN DATA



- All linear dimensions are in millimeters. Α.
  - This drawing is subject to change without notice. B.
  - C. Publication IPC-7351 is recommended for alternate designs.
  - D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations. E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.





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